



PDT-A85P4-1GA3

1.25Gbps GaAs PIN plus AGC Pre-Amplifier Photodiode in TO-46 Package, 4-pin

Overview

The Lasermate PDT-A85P4-1GA3 is a high-speed GaAs photodetector integrated with a transimpedance amplifier (TIA) in a 4-pin TO-46 package with cap lens that supports 1.25Gbps data rates at 850nm.



Features

- 850nm GaAs PIN TIA 4 pin TO
- Industry standard TO-46 package with cap lens
- Optimized for fiber optic application
- Design for short wavelength 1.25Gbps applications
- Single power supply from +3.3V

Applications

- Optimized for fiber optic application

Specifications

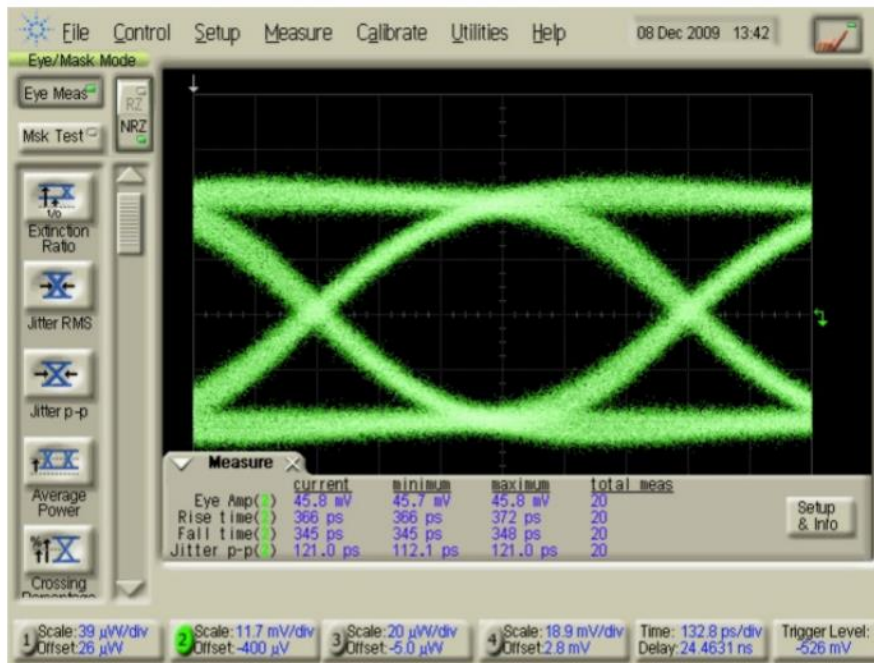
Absolute Maximum Ratings				
Parameters	Min.	Max.	Unit	Conditions
Storage temperature	-40	100	°C	
Operating temperature	-40	85	°C	
Lead solder temperature		260	°C	10 seconds

Electro-Optical Characteristics (Typical values are at + 3.3V@25°C)						
Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Power supply	V _{cc}	3.0	3.3	3.6	V	
Supply current	I _{cc}		22	30	mA	No loads
Differential responsivity	R _d	7.6		17.8	mV/uW	λ=850nm, R _{load} =100ohm, P=-24dBm
Single ended responsivity	R _s	3.8		8.9	mV/uW	λ=850nm, R _{load} =50ohm, P=-24dBm
Small-signal bandwidth	BW	700			MHz	
Low frequency cut off	LF			100	kHz	
Rise/Fall Time (20-80%)	tr/tf			400	ps	P=-24dBm, T _A =25°C
Saturation power	P _{sat}	0			dBm	
Single ended output impedance	R _O		50		ohm	
Wavelength	λ	770		860	nm	
Sensitivity				-26	dBm	λ=850nm, @1244.16Mbps, PRBS7, ER=10dB, BER=10 ⁻¹⁰

Typical Characteristics

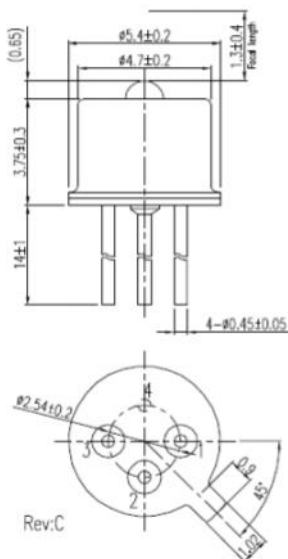
Eye Diagram

$R_{load} = 50\Omega$, $P = -24\text{dBm}$ @ 1244.16Mbps, 850nm, PRBS7.



$t_r = 366\text{ps}$, $t_f = 345\text{ps}$, Jitter p-p = 121.0ps

Outline Dimensions (unit: mm)



Pinout:

1. Vcc
2. Dout
3. Dout
4. Gnd

Note: Specifications are subject to change without notice.